

U.S. Patent No. 6,927,152
 Request for Certificate of Correction

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 APR 10 2007 Docket: CU-3494

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application:	Seung Woo JIN et al.	GRP ART UNIT: 2823
Patent No:	6,927,152]
Issue Date:	August 9, 2005	Ex.: Dang, Trung Q.
Serial No:	10/738,394]
Filed:	December 17, 2003]
For:	METHOD FOR FABRICATING SEMICONDUCTOR DEVICE	

Certification under 37 C.F.R. §1.8(a)

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I hereby certify that this paper (along with any paper referred to as being attached or enclosed) is being transmitted to the United States Patent and Trademark Office to the fax number and on the date indicated above.

 Anthony E. Anderson

**REQUEST FOR CERTIFICATE OF CORRECTION TO CORRECT ERRORS IN
 PATENT DUE TO APPLICANT'S MISTAKE (37 CFR 1.323)**

Certificate of Corrections Branch
 The Commissioner for Patents
 P.O. Box 1450
 Alexandria VA 22313-1450

Dear Sir:

This is a Request for Certificate of Correction to correct an inadvertent typographical error in claim 6 of U.S. Patent No. 6,927,152 (col. 4, line 31) and is summarized as follows:

APPLICANT'S MISTAKE (37 CFR 1.323)

With respect to Section (57) of the patent, it is noted that there is a minor typographical error in claim 6 (col. 4, line 31). A request under 35 U.S.C. 255 to correct

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the minor typographical error is submitted herein.

Claim 6 reads as follows, inter alia:

"...implantation energy of 1040KeV and a dose of 1.0E15-1.0E16."

and should read as follows:

"...implantation energy of --10—40KeV-- and a dose of 1.0E15-1.0E16."

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